

# FML12N50ES

#### **FUJI POWER MOSFET**

## Super FAP-E<sup>3</sup> series

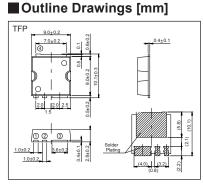
### N-CHANNEL SILICON POWER MOSFET

#### Features

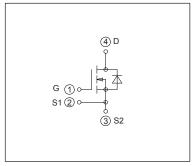
Maintains both low power loss and low noise Lower R<sub>DS</sub>(on) characteristic More controllable switching dv/dt by gate resistance Smaller V<sub>GS</sub> ringing waveform during switching Narrow band of the gate threshold voltage (3.7±0.5V) High avalanche durability

#### Applications

Switching regulators UPS (Uninterruptible Power Supply) **DC-DC converters** 







#### Maximum Ratings and Characteristics

Absolute Maximum Ratings at Tc=25°C (unless otherwise specified)

Description	Symbol	Characteristics	Unit	Remarks
Drain Source Veltore	VDS	500	V	
Drain-Source Voltage	VDSX	500	V	V <sub>GS</sub> = -30V
Continuous Drain Current	lo	±12	A	
Pulsed Drain Current	IDP	±48	А	
Gate-Source Voltage	Vgs	±30	V	
Repetitive and Non-Repetitive Maximum Avalanche Current	lar	12	А	Note*1
Non-Repetitive Maximum Avalanche Energy	Eas	460.8	mJ	Note*2
Repetitive Maximum Avalanche Energy	Ear	18	mJ	Note*3
Peak Diode Recovery dV/dt	dV/dt	6.3	kV/µs	Note*4
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note*5
Maximum Dawar Disainstian	PD	1.44	W	Ta=25°C
Maximum Power Dissipation		180	VV	Tc=25°C
On any time and Otamora Tama and time and a	Tch	150	°C	
Operating and Storage Temperature range	Tstg	-55 to +150	°C	

#### Electrical Characteristics at Tc=25°C (unless otherwise specified)

Description	Symbol	Conditions		min.	typ.	max.	Unit
Drain-Source Breakdown Voltage	BVDSS	ID=250µA, VGS=0V		500	-	-	V
Gate Threshold Voltage	V <sub>GS</sub> (th)	ID=250µA, VDS=VGS		3.2	3.7	4.2	V
Zava Cata Valtara Drain Currant		V <sub>DS</sub> =500V, V <sub>GS</sub> =0V	Tch=25°C	-	-	25	-μΑ
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =400V, V <sub>GS</sub> =0V	Tch=125°C	-	-	250	
Gate-Source Leakage Current	Igss	V <sub>GS</sub> =±30V, V <sub>DS</sub> =0V		-	10	100	nA
Drain-Source On-State Resistance	RDS (on)	I <sub>D</sub> =6A, V <sub>GS</sub> =10V		-	0.427	0.50	Ω
Forward Transconductance	g <sub>fs</sub>	ID=6A, VDS=25V		4.5	9	-	S
Input Capacitance	Ciss	V <sub>DS</sub> =25V V <sub>GS</sub> =0V f=1MHz		-	1400	2100	pF
Output Capacitance	Coss			-	160	240	
Reverse Transfer Capacitance	Crss			-	11.5	17.5	
Turn-On Time	td(on)	V <sub>cc</sub> =300V V <sub>cs</sub> =10V I <sub>D</sub> =6A R <sub>c</sub> =15Ω		-	31	46.5	- ns
	tr			-	18	27	
Turn-Off Time	td(off)			-	83	124.5	
	tf			-	16	27	
Total Gate Charge	QG	Vec=250V Ib=12A Ves=10V		-	43	56	nC
Gate-Source Charge	QGS			-	13	23	
Drain-Source Crossover Charge	Qsw			-	6	10	
Gate-Drain Charge	QGD			-	14	21	
Avalanche Capability	lav	L=2.44mH, Tch=25°C		12	-	-	A
Diode Forward On-Voltage	Vsd	IF=12A, VGS=0V, Tch=25°C		-	0.86	1.30	V
Reverse Recovery Time	trr	I <sub>F</sub> =12A, V <sub>GS</sub> =0V		-	0.37	-	μS
Reverse Recovery Charge	Qrr	-di/dt=100A/µs, Tch=25°C		-	5.0	-	μC

#### Thermal Characteristics

Description	Symbol	Test Conditions	min.	typ.	max.	Unit
Thermal resistance	Rth (ch-c)	Channel to case			0.69	°C/W
	Rth (ch-a)	Channel to Ambient			87	°C/W
	Rth (ch-a)	Channel to Ambient Note*6			52	°C/W

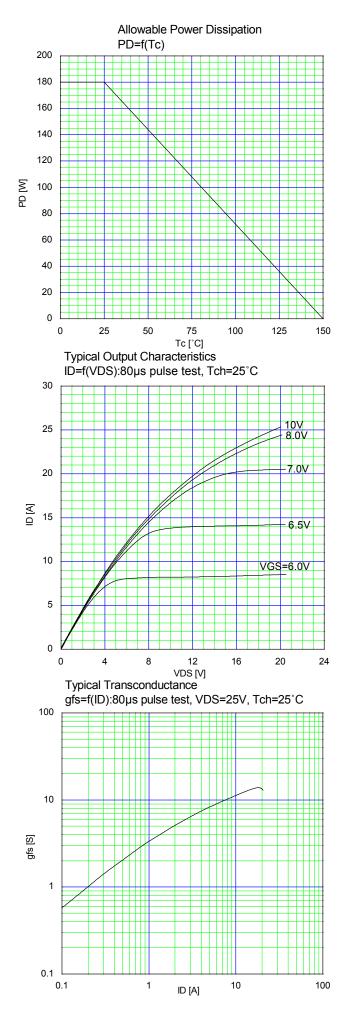
Note \*1 : Tch≤150°C

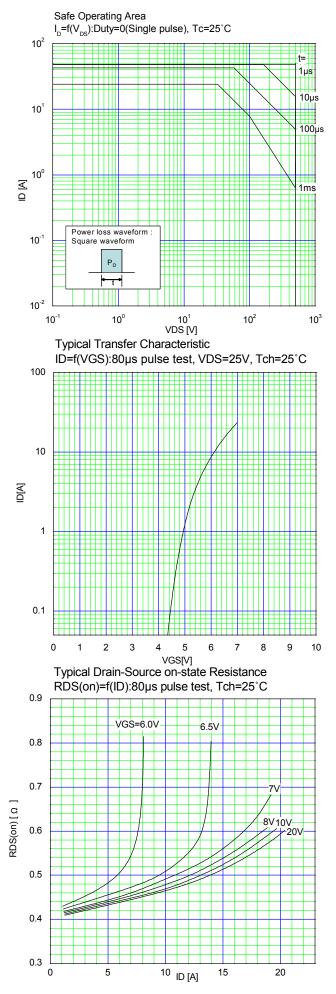
Note \*4 : IFS-ID, -di/dt=100A/µs, VccSBVDss, TchS150°C.

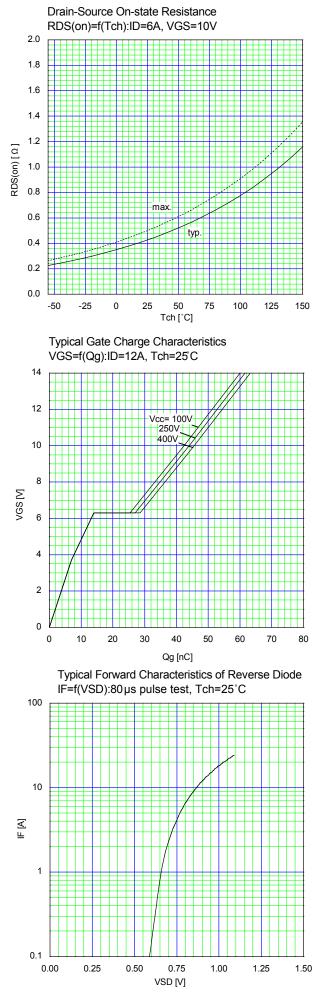
Note \*5 : I⊧≤-I<sub>D</sub>, dv/dt=6.3kV/Js, Vcc≤BV<sub>DSS</sub>, Tch≤150°C. Note \*6 : Surface mounted on 1000mm<sup>2</sup>, t=1.6mm FR-4 PCB (Drain pad area : 500mm<sup>2</sup>)

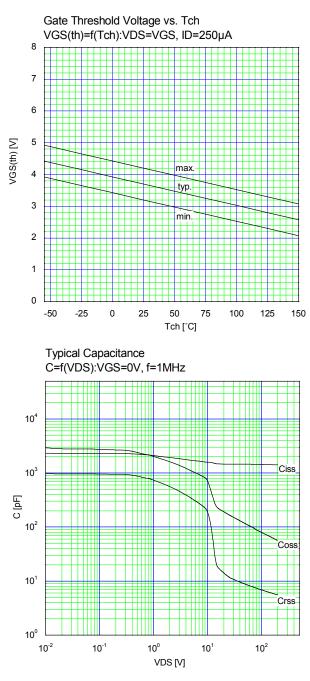
Note \*2 : Stating Tch=25°C, Ias=5A, L=33.8mH, Vcc=50V, Rg=10 $\Omega$ , Eas limited by maximum channel temperature and avalanche current. Note \*3 : Repetitive rating : Pulse width limited by maximum channel temperature

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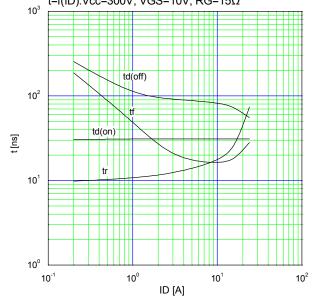




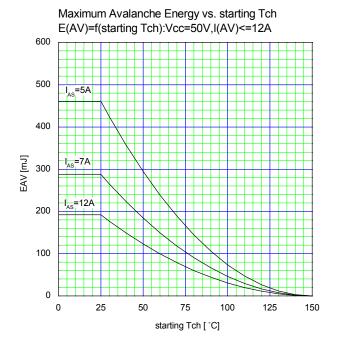


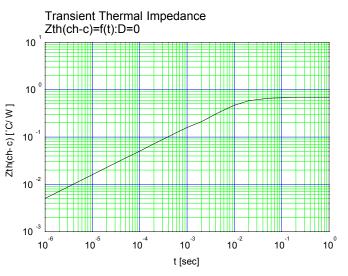


Typical Switching Characteristics vs. ID t=f(ID):Vcc=300V, VGS=10V, RG=15 $\Omega$ 



3





	WARNING
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<ul> <li>6. Do not use produce</li> <li>equipment (withoute</li> <li>Space equipment</li> <li>Submarine repeate</li> </ul>	Aeronautic equipment     Nuclear control equipment
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